5 V ECL Triple Differential 2:1 Multiplexer

Description

The MC10E457/100E457 is a 3-bit differential 2:1 multiplexer. The fully differential data path makes the device ideal for multiplexing low skew clock or other skew sensitive signals.

The higher frequency outputs provide the device with a > 1.0 GHz bandwidth to meet the needs of the most demanding system clock.

Both, separate selects and a common select, are provided to make the device well suited for both data path and random logic applications.

The differential inputs have internal clamp structures which will force the Q output of a gate in an open input condition to go to a LOW state. Thus, inputs of unused gates can be left open and will not affect the operation of the rest of the device. Note that the input clamp will take affect only if both inputs fall 2.5 V below V_{CC} .

The 100 Series contains temperature compensation.

Multiple V_{BB} pins are provided to ease AC coupling input signals. The V_{BB} pins, internally generated voltage supply pins, are available to this device only. For single-ended input conditions, the unused differential input is connected to V_{BB} as a switching reference voltage. V_{BB} may also rebias AC coupled inputs. When used, decouple V_{BB} and V_{CC} via a 0.01 μF capacitor and limit current sourcing or sinking to 0.5 mA. When not used, V_{BB} should be left open.

Features

- Differential D and Q; V_{BB} available
- 700 ps Max. Propagation Delay
- High Frequency Outputs
- Separate and Common Select
- PECL Mode Operating Range: V_{CC} = 4.2 V to 5.7 V with V_{EE} = 0 V
- NECL Mode Operating Range: V_{CC} = 0 V with V_{EE} = -4.2 V to -5.7 V
- Internal Input 50 kΩ Pulldown Resistors
- ESD Protection:
 - ♦ > 2 kV Human Body Model
 - ♦ > 200 V Machine Model
- Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test
- Moisture Sensitivity: Level 3 (Pb-Free)
 (For Additional Information, see Application Note <u>AND8003/D</u>)
- Flammability Rating: UL 94 V-0 @ 0.125 in, Oxygen Index: 28 to 34
- Transistor Count = 218 Devices
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant



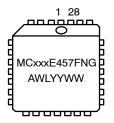
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PLCC-28 FN SUFFIX CASE 776-02

MARKING DIAGRAM*



xxx = 10 or 100

A = Assembly Location

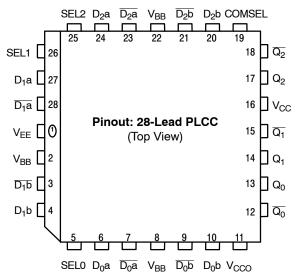
WL = Wafer Lot
 YY = Year
 WW = Work Week
 G = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping†
MC10E457FNR2G	PLCC-28 (Pb-Free)	500 Tape & Reel
MC100E457FNR	PLCC-28 (Pb-Free)	37 Units / Tube

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}For additional marking information, refer to Application Note <u>AND8002/D</u>.



^{*} All V_{CC} and V_{CCO} pins are tied together on the die.

Warning: All V_{CC} , V_{CCO} , and V_{EE} pins must be externally connected to Power Supply to guarantee proper operation.

Figure 1. Pinout Assignment

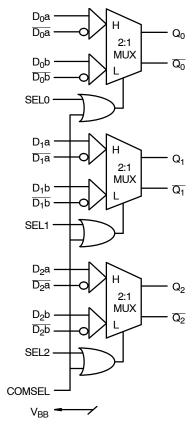


Figure 2. Logic Diagram

Table 1. PIN DESCRIPTION

PIN	FUNCTION				
Dn[0:2]; Dn[0:2]	ECL Differential Data Inputs				
SEL	ECL Individual Select Input				
COMSEL	ECL Common Select Input				
Q[0:2], \(\overline{Q}[0:2]	ECL Differential Data Outputs				
V _{BB}	Reference Voltage Output				
V _{CC} , V _{CCO}	Positive Supply				
V _{EE}	Negative Supply				

Table 2. FUNCTION TABLE

SEL	Data
H	a b

Table 3. MAXIMUM RATINGS

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V _{CC}	PECL Mode Power Supply	V _{EE} = 0 V		8	V
V _{EE}	NECL Mode Power Supply	V _{CC} = 0 V		-8	V
VI	PECL Mode Input Voltage NECL Mode Input Voltage	V _{EE} = 0 V V _{CC} = 0 V	$\begin{array}{c} V_I \leq V_{CC} \\ V_I \geq V_{EE} \end{array}$	6 -6	V
l _{out}	Output Current	Continuous Surge		50 100	mA
I _{BB}	V _{BB} Sink/Source			±0.5	mA
T _A	Operating Temperature Range			0 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
$\theta_{\sf JA}$	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	PLCC-28 PLCC-28	63.5 43.5	°C/W
$\theta_{\sf JC}$	Thermal Resistance (Junction-to-Case)	Standard Board	PLCC-28	22 to 26	°C/W
T _{sol}	Wave Solder (Pb-Free)			265	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Table 4. 10E SERIES PECL DC CHARACTERISTICS (V_{CCx} = 5.0 V, V_{EE} = 0.0 V (Note 1))

			-40°C		0°C			25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		92	110		92	110		92	110		92	110	mA
V _{OH}	Output HIGH Voltage (Note 2)				3980	4070	4160	4020	4105	4190	4090	4185	4280	mV
V _{OL}	Output LOW Voltage (Note 2)				3050	3210	3370	3050	3210	3370	3050	3227	3405	mV
V _{IH}	Input HIGH Voltage (Single-Ended)				3830	3995	4160	3870	4030	4190	3940	4110	4280	mV
V _{IL}	Input LOW Voltage (Single-Ended)				3050	3285	3520	3050	3285	3520	3050	3302	3555	mV
V _{BB}	Output Voltage Reference	3.57		3.7	3.62		3.73	3.65		3.75	3.69		3.81	V
V _{IHCMR}	Input HIGH Voltage Com- mon Mode Range (Differ- ential Configuration) (Note 3)				2.7		5.0	2.7		5.0	2.7		5.0	V
I _{IH}	Input HIGH Current			150			150			150			150	μΑ
I _{IL}	Input LOW Current				0.5	0.3		0.5	0.25		0.3	0.2		μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 1. Input and output parameters vary 1:1 with V $_{CC}$. V $_{EE}$ can vary -0.46 V / +0.06 V. 2. Outputs are terminated through a 50 Ω resistor to V $_{CC}$ 2.0 V.
- 3. V_{IHCMR} min varies 1:1 with V_{EE}, max varies 1:1 with V_{CC}.

Table 5. 10E SERIES NECL DC CHARACTERISTICS ($V_{CCx} = 0.0 \text{ V}$; $V_{EE} = -5.0 \text{ V}$ (Note 1))

		-40°C			0°C			25°C		85°C				
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		92	110		92	110		92	110		92	110	mA
V _{OH}	Output HIGH Voltage (Note 2)				-1020	-930	-840	-980	-895	-810	-910	-815	-720	mV
V _{OL}	Output LOW Voltage (Note 2)				-1950	-1790	-1630	-1950	-1790	-1630	-1950	-1773	-1595	mV
V _{IH}	Input HIGH Voltage (Single-Ended)				-1170	-1005	-840	-1130	-970	-810	-1060	-890	-720	mV
V _{IL}	Input LOW Voltage (Single-Ended)				-1950	-1715	-1480	-1950	-1715	-1480	-1950	-1698	-1445	mV
V_{BB}	Output Voltage Reference	-1.43		-1.3	-1.38		-1.27	-1.35		-1.25	-1.31		-1.19	V
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differen- tial Configuration) (Note 3)				-2.3		0.0	-2.3		0.0	-2.3		0.0	V
I _{IH}	Input HIGH Current			150			150			150			150	μΑ
I _{IL}	Input LOW Current				0.5	0.3		0.5	0.065		0.3	0.2		μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 1. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary -0.46 V / +0.06 V.
- 2. Outputs are terminated through a 50 Ω resistor to V_{CC} 2.0 V.
- 3. VIHCMR min varies 1:1 with VEE, max varies 1:1 with VCC.

Table 6. 100E SERIES PECL DC CHARACTERISTICS (V_{CCx} = 5.0 V, V_{EE} = 0.0 V (Note 1))

		-40°C				0°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		92	110		92	110		92	110		106	127	mA
V _{OH}	Output HIGH Voltage (Note 2)				3975	4050	4120	3975	4050	4120	3975	4050	4120	mV
V _{OL}	Output LOW Voltage (Note 2)				3190	3295	3380	3190	3255	3380	3190	3260	3380	mV
V _{IH}	Input HIGH Voltage (Single-Ended)				3835	3975	4120	3835	3975	4120	3835	3975	4120	mV
V _{IL}	Input LOW Voltage (Single-Ended)				3190	3355	3525	3190	3355	3525	3190	3355	3525	mV
V_{BB}	Output Voltage Reference	3.62		3.74	3.62		3.74	3.62		3.74	3.62		3.74	V
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 3)				2.7		5.0	2.7		5.0	2.7		5.0	V
I _{IH}	Input HIGH Current			150			150			150			150	μΑ
I _{IL}	Input LOW Current				0.5	0.3		0.5	0.25		0.5	0.2		μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 1. Input and output parameters vary 1:1 with $V_{CC}.\ V_{EE}$ can vary –0.46 V / +0.8 V.
- 2. Outputs are terminated through a 50 Ω resistor to V_{CC} 2.0 V.
- 3. V_{IHCMR} min varies 1:1 with V_{EE} , max varies 1:1 with V_{CC} .

Table 7. 100E SERIES NECL DC CHARACTERISTICS (V_{CCx} = 0.0 V; V_{EE} = -5.0 V (Note 1))

		-40°C			0°C			25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		92	110		92	110		92	110		92	110	mA
I _{EE}	Power Supply Current		92	110		92	110		92	110		106	127	mA
V _{OH}	Output HIGH Voltage (Note 2)				-1025	-950	-880	-1025	-950	-880	-1025	-950	-880	mV
V _{OL}	Output LOW Voltage (Note 2)				-1810	-1705	-1620	-1810	-1745	-1620	-1810	-1740	-1620	mV
V _{IH}	Input HIGH Voltage (Single-Ended)				-1165	-1025	-880	-1165	-1025	-880	-1165	-1025	-880	mV
V _{IL}	Input LOW Voltage (Single-Ended)				-1810	-1645	-1475	-1810	-1645	-1475	-1810	-1645	-1475	mV
V _{BB}	Output Voltage Reference	-1.38		-1.26	-1.38		-1.26	-1.38		-1.26	-1.38		-1.26	V
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differen- tial Configuration) (Note 3)				-2.3		0.0	-2.3		0.0	-2.3		0.0	V
I _{IH}	Input HIGH Current			150			150			150			150	μΑ
I _{IL}	Input LOW Current				0.5	0.3		0.5	0.25		0.5	0.2		μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 1. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary -0.46~V / +0.8~V.
- 2. Outputs are terminated through a 50 Ω resistor to V_{CC} 2.0 V.
- 3. V_{IHCMR} min varies 1:1 with V_{EE} , max varies 1:1 with V_{CC} .

Table 8. AC CHARACTERISTICS ($V_{CCx} = 5.0 \text{ V}$; $V_{EE} = 0.0 \text{ V}$ or $V_{CCx} = 0.0 \text{ V}$; $V_{EE} = -5.0 \text{ V}$ (Note 1))

			0°C		25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f _{MAX}	Maximum Toggle Frequency	1.1			1.1			1.1			GH- z
t _{PLH} t _{PHL}	Propagation Delay to Output D (Differential) D (Single-Ended) SEL COMSEL	325 275 300 325	475 475 500 525	700 750 775 800	375 325 350 375	475 475 500 525	650 700 725 750	375 325 350 375	475 475 500 525	650 700 725 750	ps
t _{skew}	Within-Device Skew (Note 2)		40			40			40		ps
t _{skew}	Duty Cycle Skew (Note 3) t _{PLH} - t _{PHL}		±10			±10			±10		ps
t _{JITTER}	Random Clock Jitter (rms)		<1.0			<1.0			<1.0		ps
V _{PP}	Input Voltage Swing (Differential Configuration)	150						150			mV
t _r /t _f	Rise/Fall Time 20-80%	125	275	500				150	275	450	ps

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

^{1. 10} Series: V_{EE} can vary -0.46 V / +0.06 V. 100 Series: V_{EE} can vary -0.46 V / +0.8 V.

^{2.} Within-device skew is defined as identical transitions on similar paths through a device.

^{3.} Duty cycle skew is defined only for differential operation when the delays are measured from the cross point of the inputs to the cross point of the outputs.

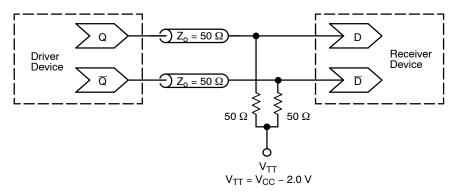


Figure 3. Typical Termination for Output Driver and Device Evaluation (See Application Note <u>AND8020/D</u> – Termination of ECL Logic Devices)

Resource Reference of Application Notes

AN1405/D - ECL Clock Distribution Techniques

AN1406/D - Designing with PECL (ECL at +5.0 V)

AN1503/D - ECLinPS™ I/O SPiCE Modeling Kit

AN1504/D - Metastability and the ECLinPS Family
AN1568/D - Interfacing Between LVDS and ECL

AN1672/D - The ECL Translator Guide
AND8001/D - Odd Number Counters Design

AND8002/D - Marking and Date Codes

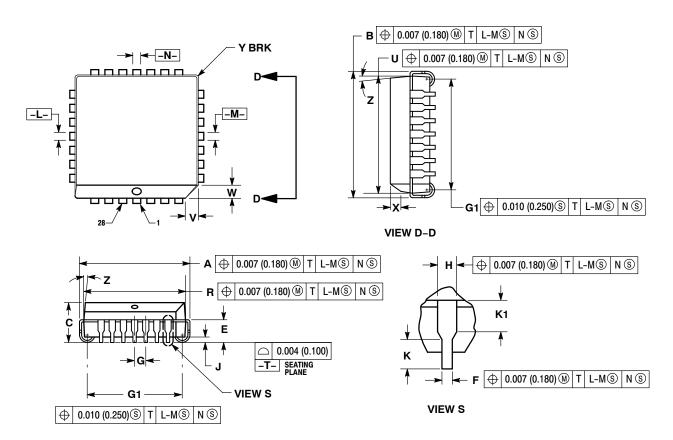
AND8020/D - Termination of ECL Logic Devices

AND8066/D - Interfacing with ECLinPS

AND8090/D - AC Characteristics of ECL Devices

PACKAGE DIMENSIONS

28 LEAD PLLC **FN SUFFIX** CASE 776-02 **ISSUE F**



- O LES:

 1. DATUMS -L-, -M-, AND -N- DETERMINED WHERE TOP OF LEAD SHOULDER EXITS PLASTIC BODY AT MOLD PARTING LINE.

 2. DIMENSION G1, TRUE POSITION TO BE MEASURED AT DATUM -T-, SEATING PLANE.

 3. DIMENSIONS R AND U DO NOT INCLUDE
- MOLD FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250) PER SIDE.
- 4. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- ANSI Y14.5M, 1982.

 5. CONTROLLING DIMENSION: INCH.

 6. THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURDS. CATE PURPS AND INTERLIED. BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.
- PLASTIC BODY TO DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.485	0.495	12.32	12.57
В	0.485	0.495	12.32	12.57
C	0.165	0.180	4.20	4.57
Е	0.090	0.110	2.29	2.79
F	0.013	0.021	0.33	0.53
G	0.050	BSC	1.27	BSC
Н	0.026	0.032	0.66	0.81
7	0.020		0.51	
K	0.025		0.64	
R	0.450	0.456	11.43	11.58
5	0.450	0.456	11.43	11.58
٧	0.042	0.048	1.07	1.21
W	0.042	0.048	1.07	1.21
X	0.042	0.056	1.07	1.42
Υ		0.020		0.50
Z	2 °	10°	2 °	10°
G1	0.410	0.430	10.42	10.92
K1	0.040		1.02	

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